NSN 5961-01-533-4937

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-533-4937 **Inclosure Material:** Glass **Overall Length:** 3.300 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** Between 0.230 inches and 0.300 inches **End Application:** An/frt-31, transmitting set, radio **Mounting Method: Terminal Terminal Circle Diameter:** Between 0.018 inches and 0.022 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 reverse voltage, dc **Current Rating Per Characteristic:** 20.00 milliamperes source cutoff current preset **Special Features:** Operating temperature: -65 to 175 degrees celsius, storage temperature: -65 to 175 degrees celsius **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: